

Research review

My research at the moment (01/04/07) Deivid Pugal



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Previously completed tasks

• Model of movement of the cations.

•
$$\frac{\partial C}{\partial t} + \nabla \cdot (-D \nabla C - zuC \nabla V) = 0$$

 Model of electric field change due to the ion movement

•
$$\nabla^2 \phi = -\rho$$







Bending model

- Assumption is that internal forces are due to charge imbalance
- No Euler beam theory
- Plane strain module, in Comsol, instead:
 - More suitable for finite element analysis
 - Dynamic instead of static solution.





Bending model - overview

- Body forces in are defined as
 - $-\nabla \cdot \sigma = \vec{F}$
 - Where σ is symmetric stress tensor and it is related to strain in the following way: $\sigma = D \varepsilon$

Where again

$$\varepsilon = \begin{bmatrix} \epsilon_{x} & \epsilon_{xy} & \epsilon_{xz} \\ \epsilon_{xy} & \epsilon_{y} & \epsilon_{yz} \\ \epsilon_{xz} & \epsilon_{yz} & \epsilon_{z} \end{bmatrix} \quad \epsilon_{i} = \frac{\partial u_{i}}{\partial x_{i}} \quad \epsilon_{ij} = \frac{1}{2} \left(\frac{\partial u_{i}}{\partial x_{j}} + \frac{\partial u_{j}}{\partial x_{i}} \right)$$

And D is elacticity matrix (inverse D is flexibility matrix).
 Includes variables such as *Poisson's ratio* and *Young's modulus*





Bending model – Rayleigh damping

- For transient analysis, we also have to consider damping!
- Comsol uses Rayleigh damping. Motion of the system:

$$m\frac{d^2u}{dt^2} + \xi\frac{du}{dt} + ku = f(t)$$

 $\xi = \alpha m + \beta k$

– So the damping parameter $\boldsymbol{\xi}$ is expressed in terms of mass m and stiffness k

• In my model:
$$\alpha = 1 \left[\frac{1}{s} \right], \beta = 0.05 [s]$$





Bending model - forces

- Force in each point of IPMC is defined as:
 - $\pmb{A}{\cdot}(\pmb{c}_{\textit{Na}}{-}\pmb{c}_{\textit{SO}})$





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Bending model - an illustration





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- Background
 - Ocillations occure due to electrochemical reactions on platinum sites in acidic environment.
 - Reactions oscillate due to changing double layer potential.
 - Reactions cause periodic contamiation of platinum sites -> conductivity change...





- Reaction mechanisms
 - CO adsorbs to active platinum sites (from HCHO) does not quite depend on DL potential -> however, causes increase of the potential.
 - Higher potential causes rapid OH adsorbtsion.
 - CO and OH react and desorb as CO2 -> causes change of the potential also





$HCHO + * \rightarrow Pt - CHO_{ads} + H^+ + e^-$

$Pt - CHO \rightarrow Pt - CO_{ads} + H^+ + e^-$

$H_2O + * \leftrightarrow Pt - OH_{ads} + H^+ + e^-$

 $CO_{ads} + OH_{ads} \rightarrow CO_2 + H^+ + e^- + 2*$





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Electrochemical oscillations







- Electrochemical oscillations occur due to poisoning of Pt surface with CO, OH
- So the Modelling:
- First, introducing the diffusion layer (for HCHO diffusion)
 - An article suggested thickness of the diffusion layer about 0.3mm
 - It means that if chemical reactions occur at the one end of the layer, then there is still const. concentration of reacting species at the other end.





Electrochemical oscillation - conc. change

 Concentration change near platinum sufrace due to electrochemical reactions - must be considered in model!







Equations - on surface of patinum electrode

 Basically, I use slight modification of equations from Doyeon's PhD thesis.

$$\begin{split} & \stackrel{\cdot}{\theta_{CO}} \neq R k_2 \cdot (1 - \theta_{CO} - \theta_{OH}) - k_4 \cdot \theta_{CO} \cdot \theta_{OH} \\ & \stackrel{\cdot}{\theta_{OH}} = k_3 \cdot (1 - \theta_{CO} - \theta_{OH}) - k_3 \cdot \theta_{OH} - k_4 \cdot \theta_{CO} \cdot \theta_{OH} \\ & \stackrel{\cdot}{E} = I_{th} + \underbrace{(I - I_{th}) \cdot R \cdot sgn(c_{HCHO} - c_{HCHO2M})}_{I + I(I - \theta_{OH} - \theta_{CO}) + k_4 \cdot \theta_{CO} \cdot \theta_{OH}) \end{split}$$



- Doyeon's model worked for 2M solution of HCHO
- This model also takes account concentration and applied constant current in range 10mA to 30mA
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Displacement and voltage oscillations

1M HCHO, 25mA/cm2

3M HCHO, 25mA/cm2





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Further goals

- Check all units and numbers. Specially everything related to diffusion layer.
- Better physical justification for addons to Doyeon's equations
- Write an article.

